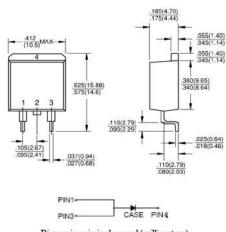
## **Surface Mount Schottky Barrier Rectifier**

Reverse Voltage - 40 V Forward Current - 25 A

## **Features**

- Low IR
- Low Power Loss / High Efficiency
- Low Forward Voltage Drop
- High Current Capability
- Highly Stable Oxide Passicated Junction
- Guard-Ring for stress Protection
- · High Surge Capability
- High ESD Capability



D<sup>2</sup>PAK

Dimensions in inches and (millimeters)

## **Mechanical Data**

Case: Molded plastic, D<sup>2</sup>PAK

Epoxy: UL 94V-0 rate flame retardant

Lead: Axial leads, solderable per MIL-STD-202, method 208 guaranteed

Polarity: As marked Mounting position: Any

## **Maximum Ratings and Electrical characteristics**

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	Value	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	40	V
Maximum RMS voltage	V <sub>RMS</sub>	28	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	40	V
Maximum Average Forward Rectified Current at T <sub>a</sub> = 25°C	I <sub>F(AV)</sub>	25	А
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	400	Α
Peak Forward Voltage at I <sub>F</sub> = 25 A	V <sub>F</sub>	0.55	V
Maximum DC Reverse Current $T_a = 25^{\circ}$ C at Rated DC Blocking Voltage $T_a = 100^{\circ}$ C	I <sub>R</sub>	0.1 20	mA
Typical Thermal Resistance	$R_{ heta JC}$	2	°C/W
Operating Junction Themerature Range	T <sub>op</sub>	- 40 to + 150	°C
Junction Temperature in DC Forward Current Without Reverse Bias.	TJ	- 40 to + 200	°C
Operating and Storage Temperature Range	T <sub>stg</sub>	- 40 to + 175	$^{\circ}$ C







